

Application Data Sheet

Application Information

Application Type:: Regular
Subject Matter:: Utility
Suggested Group Art Unit:: Not Yet Assigned
CD-ROM or CD-R?:: None
Sequence submission?:: None
Computer Readable Form (CRF)?:: No
Title:: ELECTRODE EMPLOYING NITRIDE-BASED SEMICONDUCTOR OF III-V GROUP COMPOUND, AND PRODUCING METHOD THEREOF
Attorney Docket Number:: 245402008300
Request for Early Publication?:: No
Request for Non-Publication?:: No
Total Drawing Sheets:: 4
Small Entity?:: No
Petition included?:: No
Secrecy Order in Parent Appl.?:: No

Applicant Information

Applicant Authority Type:: Inventor
Primary Citizenship Country:: Japan
Status:: Full Capacity
Given Name:: Nobuaki
Family Name:: TERAGUCHI
City of Residence:: Oji-cho
Country of Residence:: Japan
Street of mailing address:: 2-1-1-304, Katsushima, Kitakatsuragi-gun
City of mailing address:: Oji-cho
State or Province of mailing address:: Nara

Country of mailing address:: Japan

Correspondence Information

Correspondence Customer Number:: 25226

Representative Information

Representative Customer Number:: 25226

Foreign Priority Information

Country::	Application number::	Filing Date::	Priority Claimed::
Japan	2003-047701	02/25/03	Yes

Assignee Information

Assignee name:: SHARP KABUSHIKI KAISHA

Street of mailing address:: 22-22, Nagaike-cho, Abeno-ku

City of mailing address:: Osaka-shi

State or Province of mailing address:: Osaka

Country of mailing address:: Japan